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# **Ion Source Design for Industrial Applications**

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## **Introduction**

**B**ROAD-BEAM electron-bombardment ion sources are used for a wide range of industrial applications. There have been a number of reviews of the technology involved,<sup>1-5</sup> in addition to the hundreds of papers upon which these reviews were based. Despite the availability of these publications, applications of this ion-source technology have resulted in frequent design problems and much cut-and-try development. The intent of this paper is to cover some of the more frequently used design techniques, together with examples of successful component design. There is no intent of completely covering ion-source technology. The intent is, instead, to give at least one specific design example for each component, to aid those that do not have an extensive background of ion-source design upon which to draw.

The working gas Ar will be emphasized in performance calculations, although scaling relationships will be given for other gases. The presentation will be divided into sections on the gas feed, discharge chamber, ion optics, cathodes, magnetic design, and mechanical design.

It should be mentioned that single-aperture ion sources have developed almost independently of multiaperture broad-beam sources. Although this paper has been directed primarily at broad-beam sources, much of what is presented is also applicable to single-aperture sources. Where appropriate, single-aperture technology is referenced.

## **Gas Feed**

The electron-bombardment ion source requires a low pressure gas within the discharge chamber for operation. The gases used in broad-beam ion sources include at least H<sub>2</sub>, N<sub>2</sub>, Ar, Kr, Xe, Cs, Hg, and CF<sub>4</sub>.<sup>4,6,7</sup>

Single-aperture ion-source studies have included a much broader range of gases,<sup>8-10</sup> and should be consulted if more

unusual gases are of interest. A direct gas feed has been used with H<sub>2</sub>, He, N<sub>2</sub>, O<sub>2</sub>, F<sub>2</sub>, Ne, Cl<sub>2</sub>, Ar, Kr, and Xe. Also, the gaseous compounds PH<sub>3</sub>, H<sub>2</sub>S, AsH<sub>3</sub>, H<sub>2</sub>Se, SbH<sub>3</sub>, H<sub>2</sub>Te, BF<sub>3</sub>, BCl<sub>3</sub>, CO, CO<sub>2</sub>, CS<sub>2</sub>, SiF<sub>4</sub>, PF<sub>5</sub>, AsF<sub>3</sub>, SbF<sub>3</sub>, SiCl<sub>4</sub>, GeCl<sub>4</sub>, AsCl<sub>3</sub>, and SnCl<sub>4</sub> have been used in single-aperture sources.

If the vapor pressure of the material is too low to use in a direct gas feed, then an external oven or vaporizer can be used. Using this type of feed, single-aperture studies have used Li, Na, Mg, P, S, K, Ca, Zn, As, Se, Br<sub>2</sub>, Rb, Sr, Cd, In, Sb, Te, I<sub>2</sub>, Cs, Ba, Hg, Tl, and Bi, as well as the compounds BeCl<sub>2</sub>, AlCl<sub>3</sub>, MnCl<sub>2</sub>, FeCl<sub>2</sub>, SnCl<sub>2</sub>, and PbCl<sub>4</sub>.

It may appear that the element or compound being vaporized could be placed directly in the ion source, and the ion source heated to produce the proper vapor pressure. With normal ion-source cleanliness, reliable vaporization does not take place below a vapor pressure of roughly 1 Torr. But 1 Torr is decades above the normal operating pressure for an electron-bombardment ion source. The best approach, then, is to use a separate vaporizer that operates at a vapor pressure of 1 Torr, or higher. A flow restriction (orifice, porous plug, or long tube) between the vaporizer and the ion source can be used to reduce the pressure in the discharge chamber to the proper level. All hardware in contact with the gas after the flow restriction should, of course, be hot enough to avoid condensation at the local gas pressure.

The vapor pressure of most materials varies rapidly with temperature, so that accurate control of gas flow from a vaporizer requires a very accurate control of temperature. This temperature control is made more difficult by the conflicting vaporizer requirements of light thermal mass for rapid response and a high degree of temperature uniformity for an unambiguous definition of the vaporizer temperature. In practice, the vaporizer temperature is often used as only a

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rough indicator of flow, with some other parameter such as extracted beam current used for fine control of vaporizer heating power. Because of these vaporizer problems, if other factors are equal, a normally gaseous material should be chosen over one that requires a vaporizer.

Other feed techniques have been used with single-aperture sources, but are usually quite limited in utility for any sustained operation. For example, a gas of low vapor pressure neutrals can be generated within an ion source by cathode sputtering or by locally heating with a refractory filament. Excess neutral pressure is avoided by condensation of neutrals on the discharge chamber walls. But this condensation also results in rapid depletion of the material supply.

A similar condensation might be expected for low vapor pressure elements from vaporized compounds, owing to the fragmentation produced by electron collisions. In practice, other active fragments may recombine with the low vapor pressure elements on the walls almost as fast as they are deposited. Whether or not this recombination takes place will depend on the specific compound involved.

### Discharge Chamber

More complete descriptions of the discharge chamber plasma are available,<sup>3,4</sup> but a short description is included here for convenience. The neutral gas density in the discharge chamber is of the order of  $10^{13} \text{ cm}^{-3}$ , while the electron (and ion) density is roughly a decade lower. The neutrals have a random energy corresponding to the mean wall temperature. The ions are accelerated toward the boundaries to arrive at the latter with approximately the ion acoustic velocity (the minimum required velocity for a steady-state sheath solution),

$$v_a = (eT_e/m_i)^{1/2} \quad (1)$$

where  $e$  is the absolute electronic charge,  $T_e$  is the electron temperature in electron volts, and  $m_i$  is the ion mass. This ion velocity toward boundaries is many times higher than the mean neutral velocity. Thus, although the neutral density is far higher than the ion density, the extraction rate of ions can be equal to, or greater than, the neutral-loss rate.

The plasma potential is usually uniform within several volts throughout the discharge chamber, as well as being within several volts of the anode potential. For most applications, it is sufficiently accurate to assume the ions originate at anode potential.

The electrons from the cathode are injected into this plasma with an energy corresponding to approximately the full discharge voltage. They lose energy mostly by exciting or ionizing collisions with neutral atoms, the collisions being with neutrals and with background (Maxwellian) electrons (soft or Coulomb collisions). For initial electron energies greater than about 15-20 eV, the Coulomb cross section is so small that little energy is lost to background electrons, and the ionizing contribution of the high energy, or primary, electrons is important. These primary electrons make up of the order of 10% of the total electron population, with a low-energy (roughly 1-10 eV) Maxwellian population the remainder.

The mean free path for ionization due to the primary electrons is usually much greater than the discharge chamber dimensions. The containment of these primary electrons is a major design feature of the discharge chamber. This is accomplished by having surfaces at approximately cathode potential so these electrons are reflected, or by having the surfaces protected by a magnetic field that also serves to reflect them. This protection function requires a theoretical magnetic integral between the anode and cathode of

$$\int B \times dx = 6.74 \times 10^{-6} V_d^{1/2} \quad (2)$$

where the integral is in Tesla-meters and the discharge potential difference  $V_d$  is in volts.

If primary electron containment were the only consideration in choosing a value for the magnetic integral, then a very large value would often be desirable. But the magnetic field also tends to prevent the escape of Maxwellian electrons to the anode, and this escape is required to complete the discharge circuit. The proper selection of magnetic integral is thus a compromise between the value desired for primary electron containment and that desired for Maxwellian electron escape to the anode.

### Types of Discharge Chambers

For the most part, two types of discharge chambers are considered in this paper. The first, considered to a lesser extent, is the conventional axial-field chamber shown in Fig. 1. This was the first type of discharge chamber used in an electron-bombardment ion source, and is still widely used for small ion sources. For larger sources, though, this type of chamber has serious beam-uniformity problems. These uniformity problems can be partially offset by multiple cathodes.

A much more flexible approach for large ion sources is the multipole type shown in Fig. 2. Because the magnetic field in the multipole type is confined to the region near the wall, the primary electrons have free access to most of the discharge chamber volume, and a uniform plasma can be produced over a large diameter. The multipole approach is also readily adapted to arbitrary discharge-chamber shapes.

The concept of the primary electron region is important in the design-stage prediction of performance. This region is the volume that can be reached directly (without collisions) by primary electrons from the cathode. For the multipole type of chamber, this region is approximately the volume enclosed by the pole pieces, anodes, and ion optics (shown by the dashed line in Fig. 2).

For the axial-field design, the best performance is normally obtained using a magnetic-field strength at the downstream (toward the ion optics) end of the discharge chamber that is only 60-80% of that at the upstream end. In this case, the primary electron region coincides approximately with the innermost magnetic-field line that intercepts the anode, as shown by the dashed line in Fig. 1.

### Discharge Loss

The ions produced in the discharge chamber tend to go nearly equally in all directions, so that the fraction extracted to form the ion beam should be proportional to the extraction area,  $A_{ex}$ , divided by the total outside area of the primary electron region,  $A_p$ . If the energy to produce ions is roughly constant for different sources, then this energy, in electron volts per ion, should be some constant times  $A_{ex}/A_p$ . For well-designed sources, this is approximately the case, with the discharge energy for Ar being

$$\varepsilon \sim 50 A_p / A_{ex} \quad (3)$$

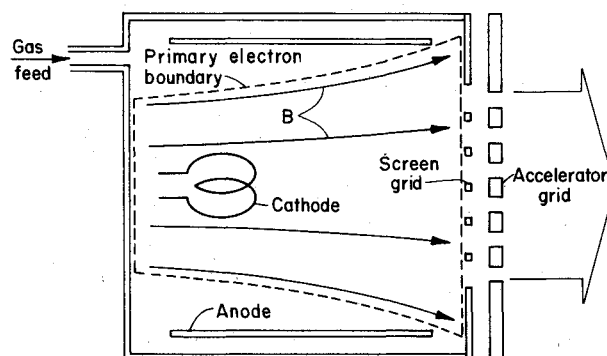


Fig. 1 Conventional axial-field discharge chamber.

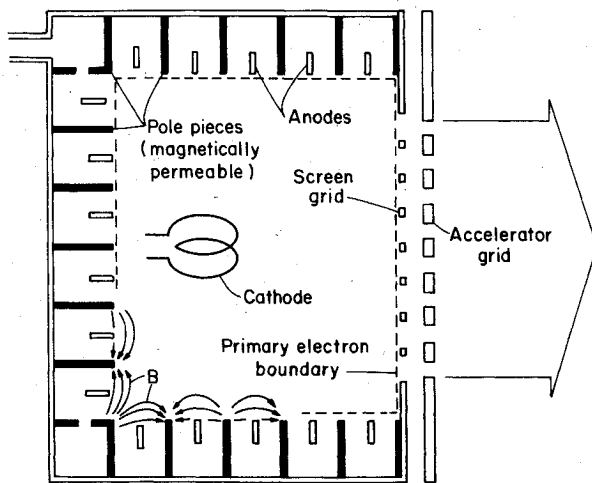


Fig. 2 Multipole discharge chamber (magnets between pole pieces not shown).

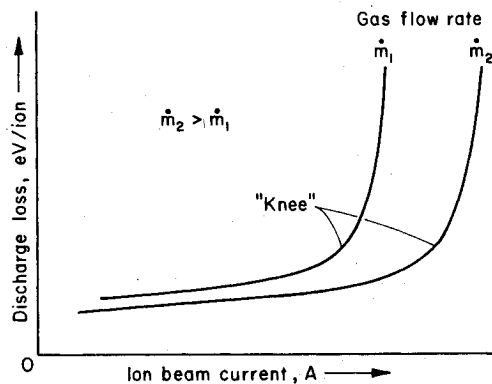


Fig. 3 Typical variation of discharge loss with extracted ion beam currents.

Note that the discharge energy  $\mathcal{E}$  in electron volts per ion also equals the discharge power in watts per beam ampere.

The discharge loss of Eq. (3) assumes operation at or near the discharge-loss "knee." As shown in Fig. 3, operation with a low beam current at some discharge-chamber neutral flow rate results in a low discharge loss. As the beam increases, the discharge loss at first rises slowly. After reaching the knee, the discharge loss rises rapidly for a small increase in beam current. If further increases in beam current are desired after reaching the knee, they are best obtained by increasing the neutral flow rate to a higher value, at the same time increasing the discharge power. The normal needs in industrial applications are a high ion beam current and a low background pressure, with the latter obtained at a low neutral flow rate. These conflicting needs are best met with operation at or near the discharge-loss knee.

The discharge loss of Eq. (3) also assumes a properly designed source. The magnetic integral should be about 1.5 times the theoretical value given by Eq. (2). (The decrease in discharge loss is usually small above a factor of about 1.5.) The screen thickness should be roughly 20% of the screen-hole diameter. As mentioned earlier, the downstream magnetic field strength of an axial-field source should be only 60-80% of the upstream value. For this type of source, the cathode should also be located downstream of any magnetic-field maximum. There is some effect of different propellants on the discharge loss, but these effects are generally within about  $\pm 30\%$ .

The relative thickness of the screen grid has an important effect on the discharge loss. A semiempirical equation for this

loss variation<sup>4</sup> is

$$\mathcal{E} \propto \exp(2t_s/d_s) \quad (4)$$

with the screen thickness  $t_s$  and screen-hole diameter  $d_s$  as defined in the Ion Optics section. For  $t_s/d_s \sim 0$ , the constant in Eq. (3) would drop to about 33, while for  $t_s/d_s \sim 0.4$ , it would rise to about 75.

Within a factor of about 2 (mostly in the increased loss direction) the same method of prediction can be used for discharge losses in single-aperture sources. The biggest difficulty usually is the estimation of the primary electron region. Some single-aperture sources resemble the axial-field source of Fig. 1,<sup>11</sup> often without the desirable decrease in field strength in the downstream direction. Others, with a magnetic-field transverse to the extraction direction,<sup>12</sup> often have a primary electron region that is only a small fraction of the total discharge-chamber volume.

#### Neutral Loss

The neutral density at the ion optics, as indicated by the source temperature and the neutral losses through the ion optics, tends toward a constant for similar operation of a particular ion source on one gas. When different ion sources are compared, the density for this similar operation varies with the ratio of primary electron region area  $A_p$  to primary electron region volume  $\Omega_p$ . The analysis of neutral loss was first conducted at the maximum utilization, where the loss curve goes nearly vertical in Fig. 3.<sup>13</sup> As discussed in connection with discharge losses, the knee of the discharge-loss curve is an operating condition of more practical interest. For knee operation and Ar as the gas, the discharge-chamber neutral density is, in  $\text{m}^{-3}$ , about

$$n_0 \sim 1.4 \times 10^{17} A_p / \Omega_p \quad (5)$$

with  $A_p$  in  $\text{m}^2$  and  $\Omega_p$  in  $\text{m}^3$ . For maximum utilization, the neutral density would be about half the value given by Eq. (5). For other monatomic gases, the required neutral density would vary approximately as  $1/\sigma m^{1/2}$ , with  $\sigma$  the maximum ionization cross section and  $m$  the ion mass. For molecular gases,  $m$  should be some mean mass including ionized fragments.

The neutral density of Eq. (5) can be given two simple interpretations. One is the external pressure in the vacuum facility that would, in equilibrium, give rise to this density. Assuming an average external temperature of  $100^\circ\text{C}$ , an average wall temperature inside the ion source of  $400^\circ\text{C}$ , and a gage calibration temperature of  $20^\circ\text{C}$ , the external facility pressure that would produce the required discharge-chamber density would be, in Torr, about

$$P \sim 6 \times 10^{-6} A_p / \Omega_p \quad (6)$$

Note that this calculation assumes some sort of ion gage that actually measures density. For different gases the pressure given by Eq. (6) should be corrected by the factor  $\sigma_{\text{Ar}} m_{\text{Ar}}^{1/2} / \sigma m^{1/2}$ . Because an ion gage gives a reading roughly proportional to ionization cross section  $\sigma$ , the uncorrected gage reading should only require correction by about the ratio  $(m_{\text{Ar}}/m)^{1/2}$  for other gases. Also note that the pressure given by Eq. (6) assumes that the rate of ion extraction is small compared to the neutral flow rate either in or out. For an ion beam that is significant compared to this neutral flow rate, the deficit due to neutrals being ionized would have to be made up by either a neutral flow direct to the discharge chamber or a higher pressure in the surrounding facility.

The other simple interpretation of the neutral density of Eq. (5) is the neutral loss rate through the ion optics for a zero surrounding facility pressure. Expressed in standard  $\text{cm}^3/\text{s}$  (at

Table 1 Clausing factor

$t/d$	$K_c$	$t/d$	$K_c$	$t/d$	$K_c$
0.1	0.909	0.6	0.632	1.2	0.471
0.2	0.834	0.7	0.597	1.4	0.436
0.3	0.771	0.8	0.566	1.6	0.406
0.4	0.718	0.9	0.538	1.8	0.381
0.5	0.672	1.0	0.514	2.0	0.359

760 Torr and 20°C), this flow rate would be

$$\dot{N}_0 = 0.85 A_0 A_p / \Omega_p \quad (7)$$

where  $A_0$  is the equivalent sharp-edged orifice area of the ion optics in  $m^2$  and both  $A_p$  and  $\Omega_p$  are as defined previously. This flow rate again assumes a negligible ion beam. Additional neutral flow will be required in the ratio of 0.249 standard  $cm^3/s$  for each ampere of beam for a singly ionized monatomic gas such as Ar. The flow rate of Eq. (7) would have to be corrected by the factor  $\sigma_{Ar} m_{Ar} / \sigma m$  for gases other than Ar.

The neutral-loss theory presented above also can be applied to single-aperture sources. In fact, similar neutral-loss theories were independently developed for single-aperture sources.<sup>14</sup>

The calculation of the equivalent sharp-edged orifice area for the ion optics,  $A_0$ , is fairly straightforward. The various ion-optics apertures usually consist of cylindrical sections, where the effective area,  $A_0$ , equals the projected open area times a Clausing factor,  $K_c$ , that depends on the length-to-diameter ratio of the cylindrical section. The values of  $K_c$  for various  $t/d$  ratios are given in Table 1.<sup>15</sup>

For ion optics in which the accelerator hole is significantly smaller than the screen hole ( $\leq 0.8 d_s$ ), it is customary to use only the impedance of the accelerator grid. If  $d_a = d_s$ , then the usual approach is to ignore the gap ( $\ell_g$ ) and simply add the two grid thicknesses to obtain an overall  $t/d$  [ $=(t_s + t_a)/d_s$ ]. Leakage can be quite important, particularly if the beam extraction dimensions are small compared to the chamber size. If the extracted ion current divided by the neutral loss is to be a high value, a thick screen grid is not desirable. The ion recombination loss on the wall of the screen grid hole would then exceed any benefit due to restriction of the neutral flow.<sup>4</sup>

#### Double Ion Production

For small ion sources at normal operating conditions, the fraction of doubly ionized atoms of a monatomic gas such as Ar can be roughly estimated from the relative cross sections. Specifically, the fraction of doubly ionized atoms approximately equals the cross section for neutral to doubly ionized divided by the cross section for neutral to singly ionized, with the energy in eV equal to the discharge potential difference in V. For Ar, the appearance potential for double ionization in a single electron collision is about 43 eV. In practice, a 10-15 cm diam source will usually have 1-2% doubly charged ions with a 40 V discharge. For much larger sources, the probability will be significant that a singly ionized atom will be struck again by an electron before it escapes from the plasma. To keep the double ion production small for a very large source, it is necessary to keep the discharge below the appearance potential for singly ionized atoms to become doubly ionized.<sup>16</sup>

It is often desirable to produce almost all singly ionized atoms in the ion beam. But it is also often desirable to produce beams with many doubly ionized atoms. The simple, direct approach for the latter is to use higher discharge voltages. This approach, however, also results in more sputtering damage. From the preceding discussion, a larger ion source would also tend to give a higher fraction of doubly ionized atoms. Such an approach, though, is often not

practical. Assuming power is not a critical parameter for the initial design, the doubly (and triply) ionized fraction can usually be increased dramatically by operating at a high discharge power loss near the minimum neutral-loss point.

To summarize the previous discussion, the doubly ionized fraction is increased by decreasing neutral pressure or flow and by increasing discharge voltage and current. The same approaches should also be effective where fragmentation of a molecule into its constituent atoms is desired.

#### Minimum Discharge Voltage

It should be evident from the discussion of double ion production that specific low values of the discharge voltage may be very desirable. It sometimes happens that the discharge cannot be maintained, except at higher voltages. The processes that determine the minimum discharge voltage should be understood, if that voltage is to be modified by design changes.

The minimum discharge voltage that can be sustained is directly related to the density-gradient driven diffusion rate for Maxwellian electrons reaching the anode. To show how the minimum discharge voltage is affected by the electron diffusion, assume that the discharge loss per ion is independent of discharge voltage. (This is approximately true.) Then assume that the discharge current is increased to produce a constant ion beam current as the discharge voltage is reduced. With a constant ion beam current being extracted, the plasma conditions (electron temperature, density, etc.) will also be nearly constant. At some point, in approximate agreement with the Bohm diffusion coefficient for anomalous diffusion, the limit is reached for density-gradient driven diffusion. For any further increase in electron diffusion (and decrease in discharge voltage), the diffusion must be aided by the anode becoming more positive than the bulk of the discharge-chamber plasma. Such an anode potential tends to be unstable in that small disturbances often result in the discharge being extinguished. The limitation in electron diffusion to the anode thus appears as the lower limit on the discharge voltage, with less diffusion capability restricting operation to higher discharge voltages.

The limitation on electron diffusion involves the area for such diffusion as well as the magnetic integral.<sup>16</sup> If the magnetic integral is  $\sim 1.5$  times Eq. (2), the diffusion area for electrons\* should typically be 60-70% of the entire primary electron region area  $A_p$ . This amount of diffusion area should permit normal operation with Ar at a discharge voltage at least down to 30-35 V. Although the effect is not a strong one, lighter gases tend to require a greater fraction of  $A_p$  for electron diffusion.

Reduction in the minimum permissible discharge voltage with the least impact on an existing design is usually accomplished by reducing the magnetic field strength. The discharge loss in one multipole chamber increased 20-30% when the field integral was reduced from 1.5 to 1.0 times the value given by Eq. (2), so the associated increase in loss can be moderate.

#### Design Calculation

As a design example, consider a multipole discharge chamber with a primary electron region (dashed line in Fig. 2) that is 10 cm in diameter and 5 cm deep. The major flow restriction to escaping neutrals is an accelerator grid that is 1.0 mm thick with a hexagonal pattern of 1.6 mm diam holes on 2.5 mm centers over an 8 cm beam diameter. Extraction is through a 0.4-mm-thick screen grid with 2.0-mm-diam holes (also on 2.5-mm centers over an 8-cm beam diameter).

The relative screen thickness,  $t_s/d_s$ , is  $0.4/2 = 0.2$ . Equation (3) may therefore be used to determine discharge losses at the

\*For an axial-field discharge chamber, the electron diffusion area is approximately the cylindrical wall area. For a multipole chamber, the electron diffusion area is the area occupied by the multipole structure.

discharge-loss "knee" (see Fig. 3). The fraction of open area for a hexagonal array of holes is  $0.9069(d_s/\ell_c)^2$ , where  $\ell_c$  is the center-to-center spacing. With 2.0-mm holes on 2.5-mm centers, the open area fraction is 0.580. For an 8-cm-diam beam, the extraction area is thus  $2.92 \times 10^{-3} \text{ m}^2$ . The total outside area of the primary electron region (a 10-cm-diam cylinder, 5 cm long) is  $3.14 \times 10^{-2} \text{ m}^2$ . The expected discharge loss, from Eq. (3), is  $50(0.0314/0.00292) = 540 \text{ eV/ion}$ . For an ion beam current of 0.1 A, for example, a 54-W discharge power would be required. For the further assumption of a 40-V discharge, the discharge current would have to be about 1.4 A.

For the neutral gas loss, the effective open area of the accelerator grid needs to be calculated. With 1.6-mm holes on 2.5-mm centers, the open area fraction is 0.371. For an 8-cm-diam beam, the projected open area is  $1.86 \times 10^{-3} \text{ m}^2$ . The 1.6-mm-diam holes through a 1.0-mm-thick accelerator grid constitute a  $t/d$  of 0.625, which corresponds to a Clausing factor  $K_c$  of 0.623. Multiplying the projected open area by this Clausing factor gives an equivalent sharp-edged orifice area of  $1.16 \times 10^{-3} \text{ m}^2$ . The primary electron region area,  $A_p$ , has already been calculated as  $3.14 \times 10^{-2} \text{ m}^2$ . The primary electron region volume (the volume of a cylinder 10 cm in diameter and 5 cm long),  $\Omega_p$ , is  $3.93 \times 10^{-4} \text{ m}^3$ . For a vacuum environment in which the backflow of neutrals into the discharge chamber is negligible, Eq. (7) can be used. Substituting for  $A_0$ ,  $A_p$ , and  $\Omega_p$  yields a neutral loss rate of 0.079 standard  $\text{cm}^3/\text{s}$ .

If an ion beam of 0.1 A is also to be extracted, an additional 0.025  $\text{cm}^3/\text{s}$  is required to supply the atoms for ion extraction (0.249  $\text{cm}^3/\text{s}$  for an ampere extracted). The total gas flow to the discharge chamber should therefore be 0.104 standard  $\text{cm}^3/\text{s}$ .

Consider next a higher pressure environment, where the discharge-chamber neutral loss is balanced by backflow from the surrounding vacuum chamber. Using Eq. (6), a required chamber pressure of  $4.8 \times 10^{-4} \text{ Torr}$  is found. If additional backflow is to be supplied for the 0.1-A extracted ion beam, the pressure should be increased by the ratio 0.104/0.079 to  $\sim 6.3 \times 10^{-4} \text{ Torr}$ .

The required gas flow to the discharge chamber is readily calculated for other pressure environments. The backflow varies linearly with chamber pressure, so that interpolation is possible between the 0.104  $\text{cm}^3/\text{s}$  required at 0 pressure up to no flow required at  $6.3 \times 10^{-4} \text{ Torr}$ .

Used correctly, calculations similar to those above can be valuable. It should be remembered that these are "knee" calculations, so that it is possible to reduce either discharge losses or neutral losses by increasing the other. It is also necessary to keep in mind that considerable error can be associated with these calculations, often up to a factor of 2. The most accurate results will always be obtained when scaling between similar designs using the same propellant. It should also be apparent that multiple ionization and/or fragmentation of molecular propellants can add further complications.

### Ion Optics

The trajectories of ions passing through the optics are determined by the potential distribution in that region, which, in turn, is determined by Poisson's equation. The one-dimensional planar solution for this equation, with zero electric field at the plane of charged-particle origin, is

$$j = (4\epsilon_0/9) (2q/m)^{1/2} (V^{3/2}/\ell^2) \quad (8)$$

where  $j$  is the current density of the charged particles,  $q/m$  is the charge-to-mass ratio of these particles,  $V$  is the potential difference between the plane of origin and any other plane, while  $\ell$  is the distance between those planes.

To obtain an approximation of the current that can be transmitted through a circular aperture of diameter  $d$ , the

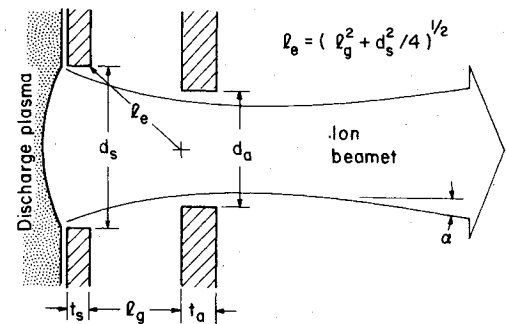


Fig. 4 Geometrical parameters for two-grid ion optics.

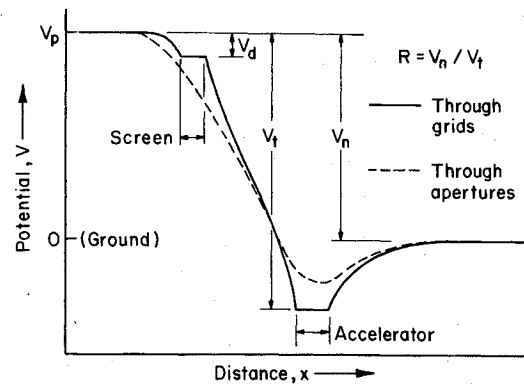


Fig. 5 Potential parameters for two-grid ion optics.

current density of Eq. (8) is multiplied by the area  $\pi d^2/4$ , giving

$$J = (\pi\epsilon_0/9) (2q/m)^{1/2} (V^{3/2}d^2/\ell^2) \quad (9)$$

For a given  $q/m$  and a fixed  $d/\ell$ ,  $J$  is seen to vary as  $V^{3/2}$ . For this reason it has been customary to present data in terms of perveance,  $J/V^{3/2}$ , rather than presenting currents separately for each voltage.

It might be expected from Eq. (9) that the effects of  $\ell/d$  could be incorporated in the perveance using the form of  $(J/V^{3/2})(\ell/d)^2$ . To date, the best correlation of experimental data and the best agreement with Eq. (9) have been obtained when  $V$  is the total voltage  $V_t$ ,  $d$  is the screen hole diameter  $d_s$ , and  $\ell$  is the effective acceleration distance  $\ell_e$ . (See Figs. 4 and 5 for definitions of geometrical and potential parameters.) Making these substitutions in Eq. (9) for  $\text{Ar}^+$  ions and rearranging the result,

$$(J/V_t^{3/2})(\ell_e/d_s)^2 = 6.79 \times 10^{-9} \quad (10)$$

The grouping of parameters on the left in Eq. (10) is called the normalized perveance, and is effective in correlating experimental ion-optics performance. The numerical value on the right is roughly the maximum normalized perveance that can be obtained without excessive accelerator impingement for  $\text{Ar}^+$  with  $d_a \sim d_s$ . For smaller accelerator holes, the maximum normalized perveance would be reduced. For other gases, the current would be expected to vary as  $(q/m)^{1/2}$ .

The degree of correlation that can be obtained using normalized perveance is indicated in Fig. 6.<sup>17</sup> The data shown were all taken at one value of discharge voltage,  $V_d$ , and one value of total accelerating voltage,  $V_t$ . Despite the different relative grid spacings,  $\ell_g/d_s$ , and the different net-to-total voltage ratios,  $R$ , all data show about the same useful ranges for normalized perveance. The right end of each curve was limited by excessive impingement, but all curves end in the range of  $3.4\text{--}3.6 \times 10^{-9} \text{ A/V}^{3/2}$ . The solid portion of each curve shows the normalized perveance where the half-angle of

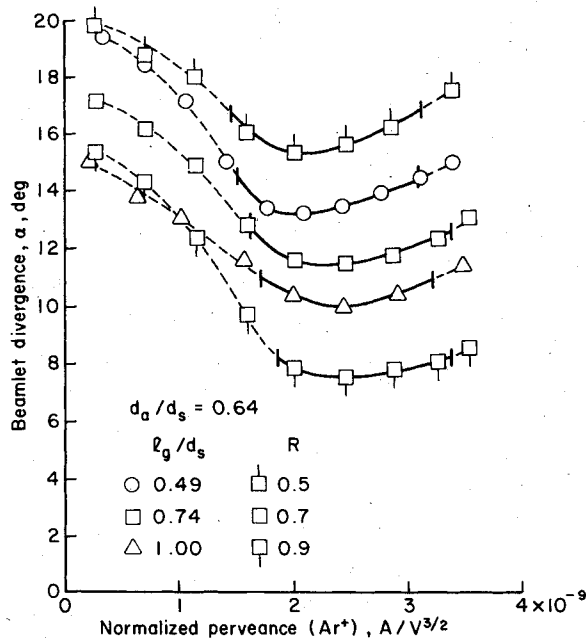


Fig. 6 Variation of ion beam divergence with operating conditions, using normalized perveance as a correlating parameter (two-grid ion optics,  $V_d/V_t = \text{const}$ ).

beam divergence was within 10% of the minimum value for that combination of  $\ell_g/d_s$  and  $R$ . The right ends of the solid curves are in the range  $3.1\text{--}3.4 \times 10^{-9} A/V^{3/2}$ , while the left ends are in the range  $1.5\text{--}1.9 \times 10^{-9} A/V^{3/2}$ . In comparison, the use of perveance (not normalized) would introduce a difference factor between maximum and minimum  $\ell_g/d_s$  (through  $\ell_e/d_s$ ) of over 2.5. The use of normalized perveance thus facilitates the comparison of performance over a wide range of operating conditions.

#### Two-Grid Optics

Two-grid optics imply a potential variation similar to that shown in Fig. 5, with the screen grid close to discharge plasma potential  $V_p$  and the accelerator grid negative relative to ground. The screen grid is usually at cathode potential, so that it is less than plasma potential by the discharge voltage  $V_d$ . The accelerator must be negative of ground by a value at least sufficient to make the potential in the center of the accelerator aperture equal to that of ground. Otherwise electron backstreaming can occur from the neutralized ion beam, giving a false indication of ion beam current and raising the beam potential in the process. With  $R$  the net-to-total voltage ratio (see Fig. 5), the maximum value of  $R$  that can be used without encountering electron backstreaming is

$$(1 - R_{\max}) \ell_e/d_a \sim 0.2 \exp(-t_a/d_a) \quad (11)$$

This equation has a semiempirical derivation,<sup>4</sup> but appears to agree well with experimental observation.

The data shown in Fig. 6 were obtained with two-grid optics. These data indicate that the normalized perveance range for best focusing and the maximum normalized perveance (limited by accelerator grid impingement) are both substantially independent of  $\ell_g/d_s$  and  $R$ .

The data of Fig. 6, as mentioned, were obtained at constant values of discharge voltage  $V_d$  and total voltage  $V_t$ . There is an effect on performance if the ratio of these voltages is not constant. The data shown in Fig. 7 indicate a clear trend toward higher normalized perveance as the ratio  $V_d/V_t$  is decreased.<sup>18-20</sup> The cause for this effect is believed to be due to the relative effect of  $V_d$  on the plasma sheath near the screen hole. The screen is customarily at cathode potential, so that the discharge plasma is positive relative to the screen by about

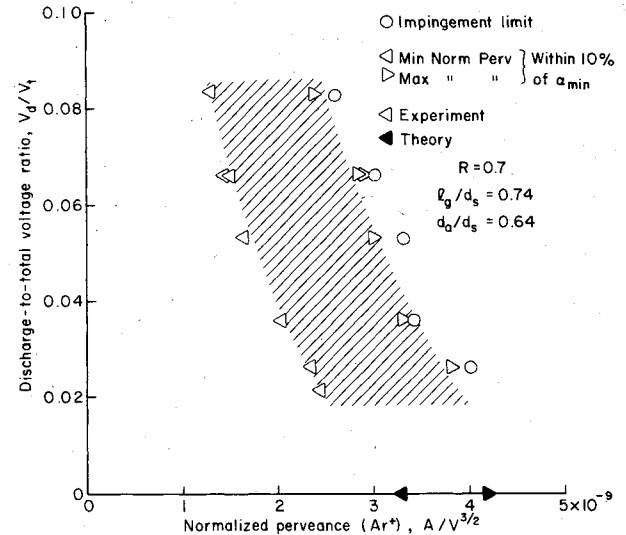


Fig. 7 Effect of discharge-to-total voltage ratio on normalized-perveance operating range for two-grid optics.

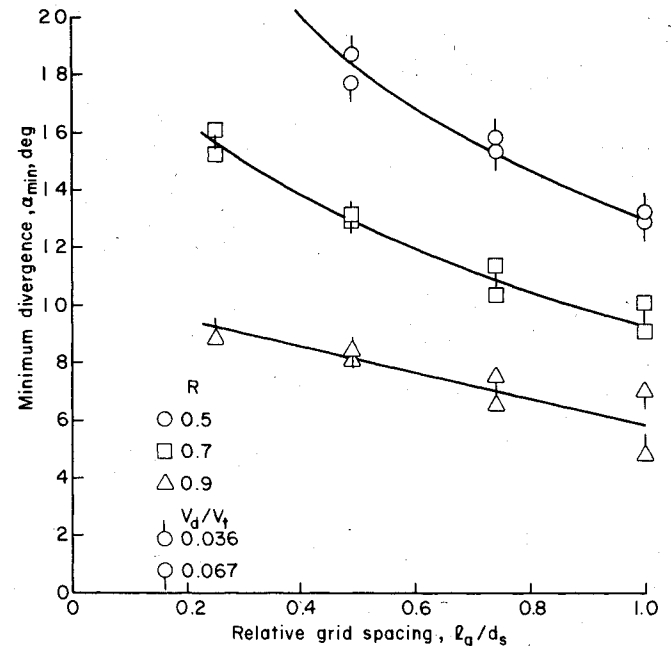


Fig. 8 Effect of relative grid spacing on minimum ion beam divergence for two-grid optics.

$V_d$ . With other voltages held constant, increasing  $V_d$  causes the sheath near the edge of a screen grid hole to recede into the discharge chamber. To retain the same degree of focusing with this sheath displacement at the edge of the hole, it is necessary to let the sheath also recede at the center of the screen hole. This latter movement is accomplished by reducing the plasma density, and hence the extracted ion current. Thus, for similar focusing, it is necessary to operate at a lower perveance as  $V_d$  is increased relative to  $V_t$ .

The explanation given above is consistent with the relative location of the theory points in Fig. 7. These points were obtained from digital computer solutions in which the discharge plasma was assumed to be at the same potential as the screen grid ( $V_d = 0$ ).

The region of best focusing has been discussed in some detail, but the degree of focusing obtained is also important. The minimum angle of divergence is shown in Fig. 8 as a function of  $\ell_g/d_s$  and  $R$ .<sup>17,18</sup> The effect of  $V_d/V_t$  on this minimum angle appears small and within the possible experimental error for most of the range of variables, with the

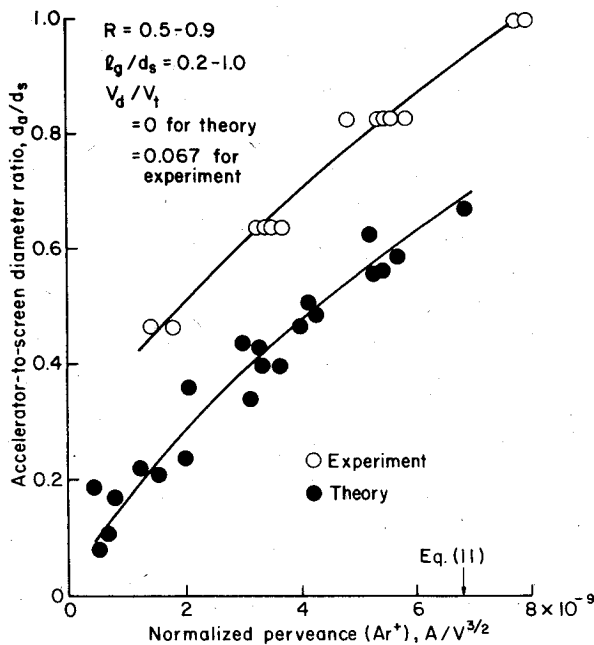


Fig. 9 Effect of accelerator hole diameter on maximum perveance for two-grid optics.

difference at  $l_g/d_s = 1.0$  and  $R = 0.9$  being a possible exception. Note that the divergence angle  $\alpha$  is actually a half-angle from the axial direction. Also, the minimum values in Fig. 8 were the reference values for the 10% increase referred to in Fig. 7.

From the data shown in Fig. 8, a further improvement in focusing would be expected for values of  $l_g/d_s > 1$ . Such values have not been investigated as part of the studies referenced above, but were evaluated as part of the fusion injection program.<sup>21,22</sup> Care should be used in comparing the two sets of data, though. The angles used for Fig. 8 are the values that enclosed 95% of the beam current. The values used most in the fusion injection program include Gaussian half-width<sup>21</sup> and rms deviation.<sup>22</sup>

The only major parametric effect left undescribed is that of the relative accelerator hole diameter,  $d_a/d_s$ . Experimental data<sup>17</sup> are shown in Fig. 9 for only one value of  $V_d/V_t$ , 0.067. Theoretical results<sup>19,20</sup> in Fig. 9 show a clear qualitative agreement with experimental data, but displaced to higher normalized perveances. Much of the perveance difference can be attributed to the difference in  $V_d/V_t$  (see Fig. 7). But detailed comparisons suggest that the experimental beamlet diameter (from a single grid hole) was actually larger and less focused than indicated by the digital computer solutions at comparable operating conditions. Some of the difference between theory and experiment appears to result from this difference in beamlet diameter.

The best method for calculating the effect of accelerator hole diameter appears to be to use Fig. 7 for the maximum normalized perveance at  $d_a/d_s = 0.64$ . Then the slope of Fig. 9 ( $\sim 8 \times 10^7$ ) can be used to correct to other values of  $d_a/d_s$ .

Two parameters do not have a significant effect on focusing or maximum perveance. Up to a value of about 0.25, the relative screen grid thickness,  $t_s/d_s$ , has little effect. In a similar manner, the relative accelerator grid thickness,  $t_a/d_s$ , has little effect up to a value of at least 0.4.

All dimensions in the preceding discussion have been given in terms of dimensionless ratios ( $d_a/d_s$ ,  $l_g/d_s$ , etc.). This approach can be justified from theoretical results [such as Eqs. (9) and (10), for example] in that only ratios of dimensions can be shown to have any significance. In practice, the absolute dimensions appear to have little importance for  $d_s > 2$  mm. For smaller values of  $d_s$ , the maximum normalized perveance is substantially decreased.

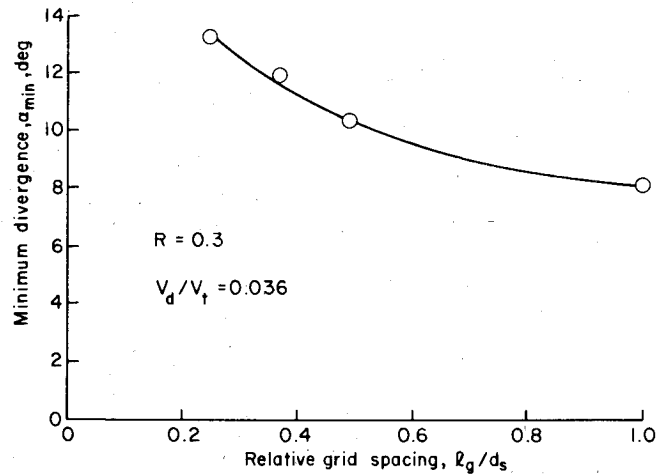


Fig. 10 Effect of relative grid spacing on minimum ion beam divergence for three-grid optics (decelerator spacing  $l_d$  equal to accelerator spacing  $l_g$ ).

The reason for this effect is not clear, but it has been verified in independent investigations.<sup>4,18</sup> It is still possible to gain in current density by going to values of  $d_s < 2$  mm, because the increase in hole density can more than offset the decreased capability of each hole. But operation with  $d_s < 2$  mm should be considered as uncertain in any new design, because of the absence of a thorough understanding of this effect. For a design estimate, one set of data indicates a decrease in maximum normalized perveance roughly in proportion to  $d_s$  below 2 mm.<sup>18</sup>

### Three-Grid Optics

For three-grid optics, a third or decelerator grid is assumed to be downstream of the accelerator and to be at ground potential. The spacing of this decelerator grid from the accelerator is  $l_d$ , while the hole diameter and thickness for this grid are  $d_d$  and  $t_d$ .

The electron backstreaming limit can be adversely affected by the presence of the decelerator grid, but Eq. (11) should still give at least a rough estimate of the limit to be expected.<sup>19,20</sup> In practice, the operating range of most interest for three-grid optics is usually at low values of  $R$ , far from the backstreaming limit.

With the additional dimensions involved in the third grid, one might expect a much more complex picture than was presented for two-grid optics. Practical considerations, however, greatly simplify this picture.

The added complexity of three-grid optics can be justified only if better performance can be obtained. The better performance is found in the excellent focusing that can be obtained at low  $R$  values. But this excellent focusing is obtained in only a narrow range of normalized perveance. Not surprisingly, this range of normalized perveance is essentially the same as the range for best focusing with two-grid optics. The relative accelerator hole diameter,  $d_a/d_s$ , of 0.64 was thus found to be effective for three-grid optics.<sup>23,24</sup> Because the beamlet tends to spread out after passing through the accelerator, a relative decelerator hole diameter,  $d_d/d_s$ , of 0.8 was found to be a good choice. Other accelerator and decelerator dimensions were tried, but did not show as much focusing advantage over two-grid optics. The relative accelerator and decelerator thicknesses,  $t_a/d_s$  and  $t_d/d_s$ , were both 0.37 for the tests described below, but the effects on focusing should be minor for values of 0 to 0.4.

Figure 10 shows the improved focusing possible with three-grid optics. Using three grids, the minimum beam divergence is far less at  $R = 0.3$  than was shown in Fig. 8 for  $R = 0.5$  and the same values of  $l_g/d_s$ . If two-grid data were available for the same  $R$  value, the difference would be even greater.

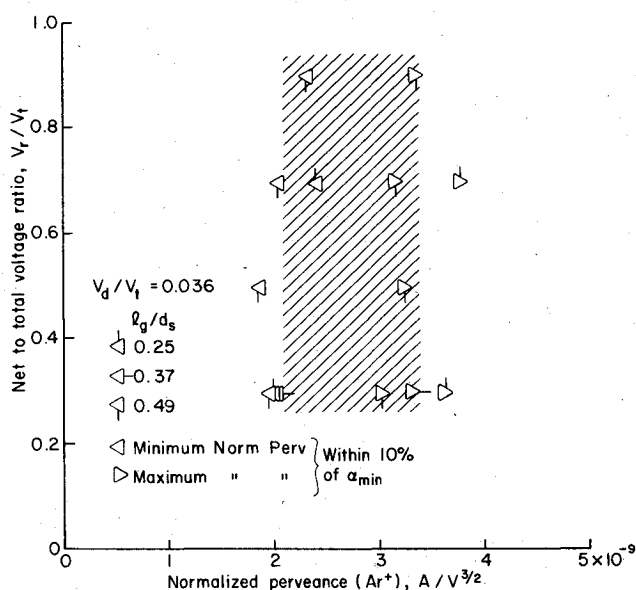


Fig. 11 Normalized-perveance operating range for three-grid optics (decelerator spacing  $\ell_d$  equal to accelerator spacing  $\ell_g$ ).

Using the same 10% increase in beam divergence from the minimum value to define operating range, Fig. 11 was constructed. For the range of variables shown, the operating range does not differ significantly from the two-grid operating range for the same value of  $V_d/V_t$ , which is shown by the shaded region.

It should be noted that no  $\ell_g/d_s = \ell_d/d_s = 1.0$  points are included in Fig. 10. This large spacing resulted in a drastic reduction of the operating range to about  $2.5\text{--}2.9 \times 10^{-9}$ . No data were obtained for relative spacings between 0.49 and 1.00, so it is not possible to state where the reduction in operating range occurs.

An additional improvement in focusing can be obtained by reducing  $\ell_d/d_s$  below the value of  $\ell_g/d_s$ . This approach should be considered where span-to-gap ratio is not a limit. The simultaneous reduction of  $\ell_d/d_s$  and  $t_d/d_s$  was not investigated, but may show additional focusing benefits, because the value of  $t_d/d_s$  generally used (0.37) was substantial compared to the range of interest for  $\ell_d/d_s$ .

#### Design Values

The design of ion optics can involve substantial uncertainties. Where possible, designs should be conservative by a margin of 20%, or more, depending on the particular problems involved. The uncertainties should be kept in mind when using the information in this section.

Ignoring grid spacings for a moment, it is possible to cover most broad-beam ion-optics applications with a limited number of designs. These designs will be called high-collimation two-grid (design I), high-perveance two-grid (design II), and high-perveance three-grid (design III). For design I,  $d_a/d_s = 0.64$ . For design II,  $d_a/d_s = 0.8\text{--}1.0$ . For design III,  $d_a/d_s = 0.64$  and  $d_d/d_s = 0.80$ . The relative thicknesses  $t_d/d_s$  and  $t_g/d_s$  will be  $\leq 0.4$ . The major effect of the relative screen thickness is on discharge loss and is discussed in the Discharge Chamber section.

The operating ranges for normalized perveance (N.P.) [left-hand side in Eq. (10)] are shown in Table 2 for designs I and III. These ranges were obtained from Fig. 7 and assume a beam divergence within 10% of the minimum for the  $\ell_g/d_s$  (and  $\ell_d/d_s$ , if three-grid) that is used.

For design II, the slope of Fig. 9 was used to correct from a  $d_a/d_s$  of 0.64 to larger values. This correction can be expressed as

$$\Delta \text{N.P.} = 1.2 \times 10^{-8} \Delta d_a/d_s \quad (\text{Ar}^+) \quad (12)$$

Table 2 Normalized perveance ( $\text{Ar}^+$ ) operating range for designs I and III

$V_d/V_t$	$d_a/d_s = 0.64 \times 10^{-9}$	
	$A/V^{3/2}$	
0.02	2.5-3.8	
0.04	2.0-3.3	
0.06	1.6-2.9	
0.08	1.3-2.6	

Table 3 Maximum normalized perveance ( $\text{Ar}^+$ ) for design II

$V_d/V_t$	$\times 10^{-9} A/V^{3/2}$	
	$d_a/d_s = 0.8$	$d_a/d_s = 1.0$
0.02	5.7	8.1
0.04	5.2	7.6
0.06	4.8	7.2
0.08	4.5	6.9

Table 4 Current per hole for various designs ( $\ell_g/d_s = 0.5$ )

$V_d/V_t$	$V_t$ , V	Designs		
		I and III, $\mu\text{A}$	Design II, $d_a/d_s = 0.8$ , $\mu\text{A}$	Design II, $d_a/d_s = 1.0$ , $\mu\text{A}$
0.02	2000	680	1020	1449
0.04	1000	209	329	481
0.06	667	99.8	165	248
0.08	500	58.1	101	154

Table 5 Minimum beam divergence for designs I and II

$\ell_g/d_s$	$R = 0.5$ , deg	$R = 0.7$ , deg	$R = 0.9$ , deg
0.25	25.2 <sup>a</sup>	15.6	8.8 <sup>a</sup>
0.49	18.3	13.1	8.2
0.74	15.6	10.9	7.1
1.00	13.2	9.6	5.9

<sup>a</sup> Data available only for  $V_d/V_t = 0.036$ .

Table 6 Minimum beam divergence for design III

$\ell_g/d_s$	$R = 0.3$ , deg	$R = 0.5$ , deg	$R = 0.7$ , deg	$R = 0.9$ , deg
0.25	13.3	...	8.0	...
0.49	10.3	8.1	7.2	6.0

With this correction, the approximate maximum normalized perveances for design II are shown in Table 3.

As a sample calculation, we can assume  $V_d = 40$  V and  $\ell_g/d_s = 0.50$ , with  $\text{Ar}^+$  ions. We could interpolate and extrapolate for other values of  $V_d/V_t$ , but only the results for 0.02, 0.04, 0.06, and 0.08 will be given. With these assumptions, the maximum currents per hole for designs I, II, and III are given in Table 4.

For other gases, these currents would be corrected by the factor  $(q/m)^{1/2}$ , as indicated by Eqs. (8) and (9). For example,  $\text{Xe}^+$  with an atomic weight of 131.3, instead of  $\text{Ar}^+$  with 39.95, would give only 55.2% of the currents shown.

The minimum divergence,  $\alpha_{\min}$ , is shown in Table 5 for two-grid optics. Except where noted, the divergence values given in this table are the averages for  $V_d/V_t$  of 0.036 and 0.067. In the absence of any additional data, these average values should probably be used for all values of  $V_d/V_t$ . The value of  $\alpha_{\min}$  does not change significantly for values of  $d_a/d_s > 0.64$ , but the beam divergence at maximum perveance



will increase. For  $d_a/d_s = 0.8$  the beam divergence increase will be up to about 4 deg at maximum perveance, while for  $d_a/d_s = 1.0$  it will be up to about 8 deg.

The minimum divergence,  $\alpha_{\min}$ , is shown in Table 6 for three-grid optics with  $\ell_g = \ell_s$ .

As for the preceding two-grid table (Table 5), these divergences are recommended for all values of  $V_d/V_r$ . The divergences for  $\ell_g/d_s = 0.49$  were also measured with a reduced value of  $\ell_g/d_s = 0.25$ , giving 8.0, 6.9, 6.7, and 6.0 deg for  $R$  values of 0.3, 0.5, 0.7, and 0.9. At a further reduction to  $\ell_g/d_s = 0.12$  the divergences were 7.6 and 6.5 deg at  $R$  values of 0.3 and 0.5.

The design procedure often consists of maximizing ion beam current for a given ion energy and a maximum acceptable beam divergence. When a design (I, II, or III) is found that will meet the divergence requirement at some operating condition, the current per hole can be maximized by reducing  $\ell_g/d_s$  and  $R$  until the divergence requirement is just met. It may be necessary to try a number of combinations of  $\ell_g/d_s$  and  $R$ , but the trial-and-error procedure for maximizing beamlet current is fairly straightforward. If more than one design will meet the maximum divergence requirement, all should be separately optimized and then compared.

To translate the current per hole into an average current density requires consideration of several limits. At low voltages, for example, it is often found that the screen holes should be as small as possible to permit more holes per unit beam area. As mentioned earlier, the screen-hole diameter should not be reduced below 2 mm without also reducing the expected current per hole. Even then, it should be kept in mind that there is limited understanding of operation with smaller screen holes.

Another limit that must be considered is the maximum permissible electric field. The best information on maximum electric field has been obtained with Hg as the working gas,<sup>4</sup> where a value of about 2 kV/mm ( $V_r/\ell_g$ ) was found for large gaps, with possibly higher fields acceptable for gaps less than 1 mm. In the absence of any specific information for Ar, this same limit of 2 kV/mm has been used. The reader should keep in mind that, in addition to the uncertainty of the maximum field for various gases, there is the uncertainty in the limit itself. The breakdown limit of 2 kV/mm represents the approximate limit imposed by frequent arcing between the screen and accelerator grids after prolonged operation. If highly polished, much higher fields can be sustained until the polished finish is degraded—sometimes by arcing. (This approach has been used in the fusion injection program.) If only conventional machining has been used, a gradual conditioning of several hours may be required to reach 2 kV/mm. This gradual conditioning may also be required if the ion optics have been exposed to the atmosphere for days or weeks.

One may find that, in the course of reducing the size of the ion optics to obtain more holes per unit beam area, this reduction is limited by the maximum permissible electric field. If the screen hole is still larger than 2 mm, there may be a current-density advantage in reducing the screen-hole diameter to 2 mm while keeping  $\ell_g$  at the minimum value. This advantage results from the current per hole being a function of the effective acceleration distance  $\ell_g$ , while the maximum electric field is a function of  $\ell_g$ . A further increase in current density may then be obtained by decreasing  $R$  slightly, to offset the improved focusing that results from the increased  $\ell_g/d_s$ .

Another limit that must be considered is that of the minimum stable and predictable value of  $\ell_g$ . This may result from machining tolerances, but more often is associated with the span-to-gap limit in broad-beam ion optics. The span-to-gap limit will be discussed further in the Mechanical Design section.

The focusing of a broad ion beam by the systematic deflection of beamlets may be of interest to either increase the

current density at a target, or to increase the target area that is uniformly covered (defocusing). There are two techniques that are frequently used to accomplish the deflection of beamlets. One is to use spherically dished grids and to align apertures along radial lines. This technique is straightforward and can be used to obtain large increases in current density on small targets or, conversely, large increases in target area covered at the same target distance. In either case the problem is resolved by geometrical considerations that are almost self-evident.<sup>25</sup>

The other frequently used technique for deflecting beamlets is aperture displacement. If an accelerator aperture is displaced in one direction (normal to the ion velocity), the beamlet will be deflected in the opposite direction. The amount of deflection that can be obtained in this manner is limited by beamlet impingement on the side of the accelerator hole. In practice, this maximum deflection is roughly equal to the beamlet divergence angle  $\alpha$ . The theory of beamlet deflection by aperture displacement has been tested and is readily available for application.<sup>25</sup> The small magnitude of the maximum possible deflection has limited the use of the aperture-displacement technique in industrial applications.

A type of optimization that is often encountered is maximizing the ratio of extracted ion current to neutral loss. For a large extracted ion current, a large accelerator hole diameter is desired. But to reduce neutral losses, small accelerator holes are desired. To resolve this apparent conflict, it is necessary to examine experimental data. It is, of course, necessary to use a large number of small screen holes to increase the extracted current. For the same reason the gap  $\ell_g$  should be as small as possible to be consistent with focusing, electric-field, and span-to-gap limits. Assuming that these parts of the optimization are handled correctly, though, what should be the value of  $d_a/d_s$ ? The answer to this question is found by plotting the ratio of normalized perveance divided by  $K_c (d_a/d_s)^2$ , where  $K_c$  is the Clausing factor given in Table 1. For reasonable assumptions of accelerator thickness, the above ratio usually optimizes close to a value of 0.64 for  $d_a/d_s$ . Since this is also a value consistent with small divergence angles, it will usually be a satisfactory final choice. Design II should therefore also be considered when the ratio of ion current to neutral loss is to be maximized.

## Cathodes

Refractory metal cathodes are widely used and represent the present technology level. Other means of emitting electrons will clearly be of increasing interest in the future,<sup>5</sup> but only refractory cathodes will be discussed herein.

### Discharge-Chamber Cathode

The optimum operating condition for a discharge-chamber cathode will depend on the exact environment involved. From experience, though, a reasonable place to start in cathode optimization is at an electron emission current density of about 1 A/cm<sup>2</sup>. The values in Table 7 were calculated for this current density and a range of wire sizes using available information on Ta and W.<sup>26</sup>

Table 7 Filament emitter properties for emission density of 1 A/cm<sup>2</sup>

Wire diam, mm	0.25	0.38	0.51	0.64	0.76
in.	0.010	0.015	0.020	0.025	0.030
Emission, A/cm	0.08	0.12	0.16	0.20	0.24
Ta (2480 K)					
A	5.1	9.4	14.4	20.1	26.5
V/cm	0.94	0.77	0.67	0.60	0.54
W (2640 K),					
V/cm	1.03	0.84	0.73	0.65	0.59

With nonreactive gases, W has the advantage of not sagging at high temperatures, but becomes very brittle after use. In contrast, Ta retains good ductility after use, but sags when cantilever shapes are heated. For nonreactive gases the lifetime should be several tens of hours at  $V_d \sim 40$  V for a cathode wire diameter of 0.25 mm. The lifetime should increase nearly proportional to the wire diameter when larger sizes are used. Careful control of contaminants can increase the lifetime substantially, while additional contaminants can greatly reduce it. (Contaminants include gases and backspattered materials from targets in sputtering applications.) If the contamination level is low, cathode lifetime is determined primarily by sputtering erosion due to ions. This means that cathode lifetime is strongly dependent on the discharge voltage.

Reactive gases can reduce the lifetime of a 0.25-mm cathode to an hour or so. Using a mixture of inert and reactive gases will give added lifetime if 100% reactive gas is not required. Ta and W often show different sensitivities to contaminants and reactive gases, so that it may be desirable to try both.

As a short example of using the previous table, consider the use of 0.25-mm Ta wire to emit 1.0 A of electrons. From the emission/cm (0.080), a 12.5 cm length will be required. If the cathode is to be a single segment, a heating current of 5.1 A is indicated. For a 12.5 cm length, the voltage should be  $12.5 \times 0.94 = 11.75$ . Because of tolerance variations in wire diameter, a current of at least 6 A should be available from the heater power supply, even if no other wire size will ever be used. To allow for contact resistances and lead losses, 15-20 V should be available. If a very short cathode segment is to be used, remember that there is little emission for several millimeters near cathode supports due to cooling effects.

#### Neutralizer Cathode

The emission capability is usually not a significant parameter for the neutralizer. Instead, the current limitation due to the space-charge effect is much more important.

The space-charge effect for a neutralizer can be approximated with electrons only between the neutralizer and a virtual anode located at a radius  $r$  from the neutralizer, such that the electron density there equals the background ion density.<sup>†</sup> For equal charge density at this radius, it is necessary that

$$j_e/j_i = (m_i V_c / m_e V_n)^{1/2} \quad (13)$$

where  $j_e$  is the electron current density at the radius  $r$ ,  $j_i$  the local ion current density,  $m_i$  the ion mass,  $m_e$  the electron mass,  $V_c$  the neutralizer-to-beam coupling voltage, and  $V_n$  the net voltage through which the ions have been accelerated. The electron current density of Eq. (13) can also be expressed as an electron emission per unit neutralizer length,

$$J_e/\ell_n = 2\pi r j_i (m_i V_c / m_e V_n)^{1/2} \quad (14)$$

For a neutralizer with a radius that is small compared to the virtual anode radius,<sup>‡</sup>  $r$ , the emission per unit neutralizer length is<sup>27</sup>

$$J_e/\ell_n = (8\pi\epsilon_0/9) (2q/m_e)^{1/2} V_c^{3/2}/r \quad (15)$$

It may be interesting to the reader that calculating this current as a density over the area  $2\pi\ell_n r$  results in a very close resemblance between this radial flow equation and Child's law, Eq. (8). Equating the two expressions for  $J_e/\ell_n$  and solving for  $r$ ,

$$r = (2\epsilon_0^{1/2}/3) (2q/m_i)^{1/4} V_c^{1/2} V_n^{1/2}/j_i^{1/2} \quad (16)$$

<sup>†</sup>Outside of this virtual anode, the initial velocity of the electrons should be rapidly randomized as the result of two-stream instability.

<sup>‡</sup>This assumption is only roughly true, but the following neutralizer calculation is only intended to be approximate.

With numerical values of the various constants substituted and the ion mass expressed in atomic mass units (amu) per electronic charge,

$$r = 2.338 \times 10^{-4} V_c^{1/2} V_n^{1/2} / j_i^{1/2} m_i^{1/4} \quad (17)$$

$$J_e/\ell_n = 268.3 r j_i (m_i V_c / V_n)^{1/2} \quad (18)$$

These equations should be used by substituting specific values for  $V_c$ ,  $V_n$ ,  $j_i$ , and  $m_i$  into Eq. (17). Then these same values, together with the value of  $r$  obtained, are substituted into Eq. (18) to obtain  $J_e/\ell_n$ .

As a specific example in the use of these equations, let the ion beam be 500-eV Ar<sup>+</sup> ions (39.95 amu) at 1 mA/cm<sup>2</sup> (10 A/m<sup>2</sup>). With these values substituted, Eqs. (17) and (18) become

$$r = 1.391 \times 10^{-4} V_c^{1/2} \quad (19)$$

$$J_e/\ell_n = 758.4 r V_c^{1/2} \quad (20)$$

The results are presented in Table 8 for a range of assumed coupling voltages,  $V_c$ .

If a total electron neutralization current of 0.1 A is necessary, a coupling voltage of 5 V would require a neutralizer length of about 20 cm, while 10 V would require a length of about 9 cm. The voltage drop along the neutralizer due to the heating current should be included in any evaluation. If necessary, a numerical integration can be performed along the neutralizer. It frequently occurs that almost all the neutralizer emission comes from only a part of the total neutralizer length near the negative end.

Note that the emission per unit length in Table 8 is less than what would be expected for 1 A/cm<sup>2</sup> from a 0.25 mm wire, except for a coupling voltage of 100 V. This means, if a low coupling voltage is desired, that the neutralizer length is usually more important than the diameter. Since sputtering contamination of the neutralizer will increase directly with the projected area struck by electrons, a thin neutralizer is the preferred configuration for low contamination.

The lifetime of a neutralizer in nonreactive gases is determined primarily by sputtering. For a 1-2 mA/cm<sup>2</sup> beam of 500 eV Ar<sup>+</sup> ions, one should expect 10-20 h of life. Lifetime should decrease with an increase in ion energy, but at less than a linear rate. Because of the sputtering erosion mechanism, life will increase with a neutralizer diameter increase, but so will contamination, as discussed above. As with the main cathode, reactive gases can drastically reduce neutralizer lifetime.

A neutralizer immersed in the ion beam was assumed for these calculations. If the neutralizer is placed outside of the ion beam, in the surrounding charge-exchange plasma,<sup>28</sup> the coupling becomes much more of a problem. In general, an immersed neutralizer is needed to neutralize a broad ion beam. If the beam is directed against a conductor so that current neutralization is not required, or if the beam is a low current one at high energy, then it may be possible to couple adequately from a neutralizer outside of the ion beam. Otherwise, use of an external refractory cathode will usually result in coupling voltages of several hundred to several thousand volts.

#### Magnetic Design

A permanent magnet design is usually simpler, cheaper, and more reliable than an electromagnet design. The

Table 8 Neutralizing coupling parameters for 1 mA/cm<sup>2</sup> of 500-eV Ar<sup>+</sup> ions

$V_c$ , V	5	10	20	50	100
$r$ , m	0.31	0.44	0.62	0.98	1.39
$J_e/\ell_n$ , A/cm	0.005	0.011	0.021	0.053	0.105

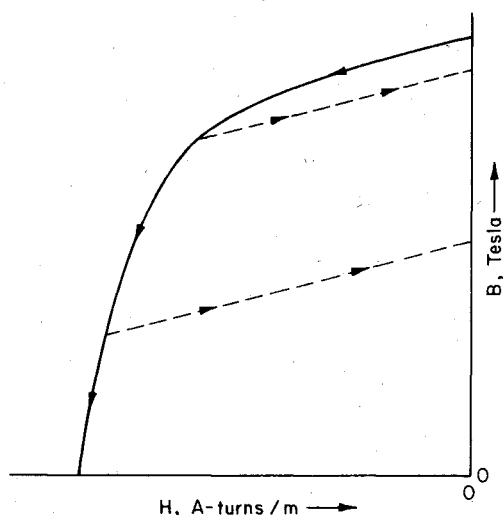


Fig. 12 Demagnetization curve for permanent magnet (solid line).

preferred type of permanent magnet is usually Alnico V because it is readily available, has a high demagnetization temperature, and has worked well in many past designs.

#### Permanent Magnets

The demagnetization curve for a permanent magnet material is indicated in Fig. 12, with the demagnetization following the solid line in the direction indicated by the arrows. If the demagnetization process is reversed, the recovery will follow different paths as indicated by the dashed lines. For normal ion-source design, the magnet is more demagnetized in an isolated state than it is when installed between permeable pole pieces. So the left ends of the dashed lines should correspond to isolated magnets. For Alnico V a length-to-diameter ratio of 4:1, when isolated, would correspond to about the left end of the upper dashed line, with little permanent loss in flux density due to demagnetization. A smaller length-to-diameter ratio would correspond to a lower dashed line with a greater permanent loss.

For the calculations herein, a flux density of 1.0 T will be assumed for an Alnico V magnet with a length-to-diameter ratio of  $\geq 4:1$ , whether isolated or installed between pole pieces. For shorter magnets than 4:1, the flux density should be reduced in proportion to the length-to-diameter ratio.

Actual flux densities can be expected to vary from the above approximate values. To keep the variation from being even greater, the handling of the permanent magnets should be carefully controlled after magnetization.

#### Pole Pieces

The usual design approach is to have permanent magnets extend between permeable pole pieces, which are made of mild (low-carbon) steel. If corrosion resistance is a concern for the pole pieces, 400 series stainless steel (ferromagnetic) should be considered.

As indicated in the discussion of the permanent magnets, the flux through the magnets does not vary significantly with the pole-piece design. The total flux can therefore be calculated directly from the total cross section of the magnets used. Also, the permeability of the pole pieces is quite high, so that the magnetic impedance of the pole pieces can be ignored compared to that of the air (or vacuum) gap. The latter can be assured to be approximately true by avoiding saturation. To this end, the average flux density at any section should not exceed about 1 T. Because the maximum flux density is usually found where the magnet contacts the pole piece, this is the region to check against the 1 T value. With 1 T within the magnet, this 1 T condition is met by making the pole piece thickness at that location equal to at least one-fourth of the permanent magnet diameter.

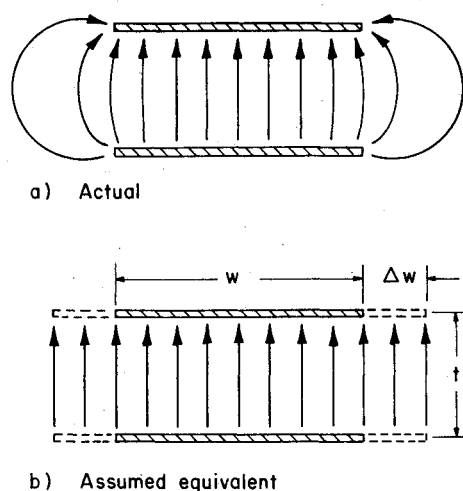


Fig. 13 Magnetic-field shape between pole pieces.

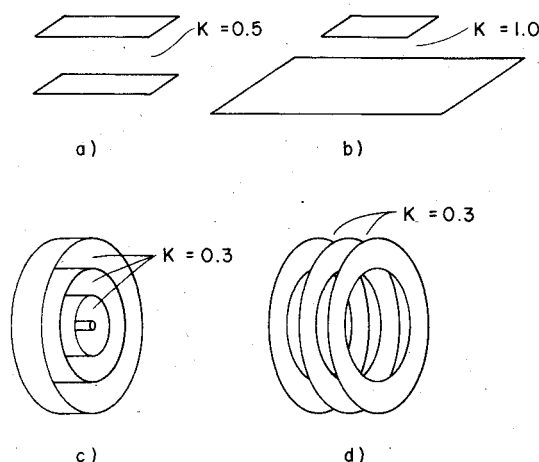


Fig. 14 Fringe-field constants for several pole-piece configurations.

For purposes of design, the pole pieces will be assumed to be parallel, thin, and separated by magnets. The magnetic-field shape between two such pole pieces is indicated in Fig. 13a. For the purposes of calculation, an assumed equivalent field shape will be used, shown in Fig. 13b. In the equivalent, the field is assumed to have a uniform strength throughout the gap, but the pole pieces are assumed to extend an additional distance  $\Delta w$  in all directions. This distance  $\Delta w$  is related to the spacing between pole pieces,  $t$ ,

$$\Delta w = Kt \quad (21)$$

with  $K$  a constant depending on pole-piece configuration. Figure 14 shows several typical pole-piece configurations and the associated values for  $K$ . The value of  $K$  for two isolated parallel pole pieces of equal size, Fig. 14a, is well known from potential-field studies as approximately 0.5. When one of two isolated pole pieces is much larger than the other, Fig. 14b, the value of  $K$  is 1.0. (With a little reflection, it should be evident that the potential solution for Fig. 14b is equivalent to half that for Fig. 14a. The factor of 2 in  $K$  follows directly from this equivalence.) For closely spaced pole pieces, in either radial or axial configurations as indicated in Figs. 14c and 14d,  $K$  is about 0.3. This value of 0.3 has been approximately determined by a number of hardware tests, but has not yet been supported by more fundamental potential-field studies.

The configurations shown in Figs. 14c and 14d imply that there is no difference between the value of  $K$  for end pairs of pole pieces and the value of  $K$  for pairs far removed from the

end. For an end pair, with field interference on only one side, a value midway between 0.3 and 0.5 might be expected. Tests to date have not been very precise, but indicate that  $K$  should be closer to 0.3 than 0.5. For this reason, no distinction is made between the end pair of a long array of poles and other pairs.

Another special case concerns the corner pole pieces, where the cylindrical wall of the discharge chamber meets the back wall. The added interference of this corner location has been taken care of by recessing the corner anodes, by an amount equal to 10% of the pole-piece spacing. This recessed anode location has been indicated in Fig. 2.

### Design Example

Consider a multipole chamber with a 10 cm inside diameter. The outer wall pole pieces (Fig. 14d) are assumed to be 2.5 cm wide and 2.5 cm apart. These particular values were chosen to give adequate space for an anode and insulated supports (including sputter shields). The pole pieces involved should thus have inside and outside diameters of 10 and 15 cm. Also assume that the magnetic integral protecting an anode with a 10 cm inside diameter is desired to be  $70 \times 10^{-6}$  T-m (70 G-cm).

The fringe field in the equivalent field shape, Fig. 13b, is assumed to be located within 0.3 times the pole-piece spacing, or  $0.3 \times 2.5 = 0.75$  cm. For an integral of  $70 \times 10^{-6}$  T-m over 0.75 cm, the field strength must be 0.0093 T. The effective area over which this field must be produced is an annulus with an inside diameter of 8.5 cm [ $10 - (2 \times 0.75)$ ] and an outside diameter of 16.5 cm [ $15 + (2 \times 0.75)$ ]. The total flux for this area is  $0.0093 \times \pi(0.0825^2 - 0.0425^2) = 1.46 \times 10^{-4}$  webers. The magnet cross-section area to support this flux at a 1 T flux density is simply  $1.46 \times 10^{-4}$  m<sup>2</sup>. If the magnets to be used are 6 mm in diameter, the cross-section area of one magnet is  $2.83 \times 10^{-5}$  m<sup>2</sup> and five magnets should be used to approximate the desired total flux. For a 6 mm diam of permanent magnets, the pole-piece thickness should be  $\geq 1.5$  mm. With a magnet length of  $\sim 25$  mm, the minimum length-to-diameter ratio of 4 is also satisfied.

The calculation is similar for the pole pieces at the end of the discharge chamber, Fig. 14c, except that the anode and the flux density are assumed to be at a mean radius between the two pole pieces of interest. Keep in mind that magnetic circuit calculations can involve large errors. It is generally necessary for the field strength to be measured and adjustments made after construction. The adjustments made are usually in the strength and/or number of permanent magnets. Again, careful handling of the permanent magnets is essential for predictable performance.

For field measurement, it is at first usually necessary to measure the field strength at enough points to permit numerical calculation of the integral protecting the anode. This integral should show a close relationship to the maximum field strength on a plane midway between the pole pieces. After a few comparisons of the integral and maximum values, the maximum can be used to replace more detailed integral measurements. In the design under consideration, the measured maximum value should be roughly the assumed value of 0.0093 T (93 G) for the desired integral of  $70 \times 10^{-6}$  T-m.

### Mechanical Design

The general construction of an ion source can be divided into conductors and insulators. For conductors, construction is usually of types 304 and 18-8 stainless steels. If either a higher temperature capability ( $> 500^\circ\text{C}$ ) or more resistance to warping is required, Mo, Ta, W, or graphite should be considered. Mo and Ta are readily machined but expensive. W can be very expensive to fabricate. Graphite has limited strength and outgasses badly after exposure to the atmosphere, but it is economical and easily machined. Pole

pieces will usually require mild steel or 400 series stainless steel for magnetic properties.

For insulators, machinable glass, quartz, alumina, and boron nitride should be considered. Machinable glass has been introduced only recently, but is easily machined to close tolerances and is useful in the lower temperature applications. Quartz is generally used only as tubing. For general purpose insulators at moderately high temperatures, alumina is the preferred material. If machined green (before firing), allowance must be made for dimensional changes during firing. Stock parts of alumina usually fall in this category, with large dimensional variations. If machined after firing, machining becomes very expensive. Boron nitride is expensive, but easy to machine. It also has fragility and outgassing problems similar to graphite. If required for its high temperature capability, boron nitride should be subjected to only mild electrical stress, if possible. If a high electrical stress is necessary, outgassing should be thorough before the electrical stress is applied.

Special requirements of some of the individual components will be described in the remainder of this section, together with some of the design approaches that have been used. It should be kept in mind that there is seldom only one satisfactory way to design a machine. The approach used is consistent with using an ion source that is separate and distinct from the vacuum chamber walls. This approach permits thin walls for the ion source and avoids the need for vacuum tight electrical feedthroughs within the ion source. It also usually results in the requirement for heat rejection from the source by radiation, but this has not proved to be a problem in most applications.

### Isolators

Unless the propellant supply is to be operated at ion-source potential, it is necessary to provide electrical isolation somewhere between the propellant supply and the ion source. Only limited tests have been conducted, but the isolation requirement appears easy to meet for nonreactive gases.

An isolator for Ar was built and tested using a 3.2 mm i.d. alumina tube, with stainless steel tubing inserted into both ends.<sup>29</sup> Two single segment lengths,  $\ell_s$  in Fig. 15a, of 7.7 and 18.4 cm were tested, with breakdown voltages in the 400-600-V range for both over a wide range of gas flow rates and an operating ion source. The three segment isolator (5.8 cm per segment) showed an average breakdown voltage per segment of 300 V, or more. The reduced minimum per segment (300 vs 400 V) is probably due to uneven voltage division between segments.

The breakdowns were visible as glows within the alumina tube when they occurred. The stainless steel tube between the isolator and ion source was curved and had an internal length-to-diameter ratio of more than 140:1. Despite this physical isolation, the breakdown voltages were several times higher with the ion source not operating. It appears clear that some charged particles were traversing the long curved path from

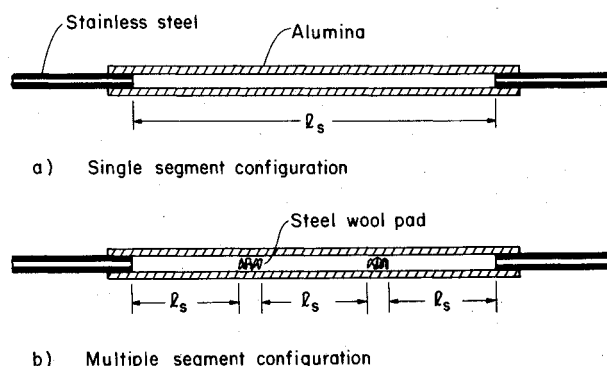


Fig. 15 Isolators for ion-source gas supply.

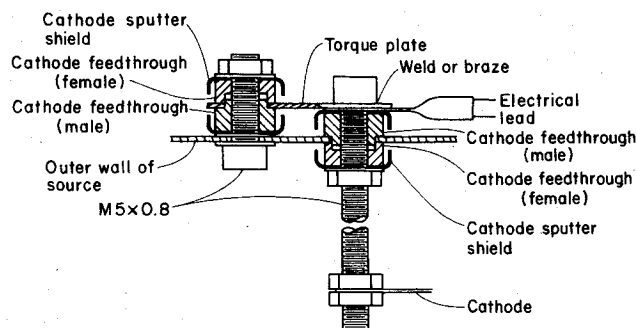


Fig. 16 Cathode support assembly.

the ion source while it was operating. This mobility of charged particles should be kept in mind when designing isolators.

The isolator concept should work well with almost any nonreactive gas. A sufficient number of segments should be provided to assure adequate breakdown voltage. A conservative approach should be to assume the Paschen-law minimum as the average per segment (typically 100-300 V). If the gas is condensable (such as Hg), the isolator should, of course, be hot enough to avoid condensation. Much shorter segment lengths than described here were used with Hg, with no apparent adverse effect.

Too high a temperature can cause problems for long-term operation. The combination of electric-field stress and temperatures above 300°C was found to result in the surface migration of contaminants and eventual breakdown with Hg gas. If the isolator temperature is low enough, assembly can be simplified by using epoxy cement.

Nonreactive gases have been emphasized in this discussion. As a contrary example, considerable work was done on isolators for Cs in the space propulsion program, with little long-term reliability achieved.

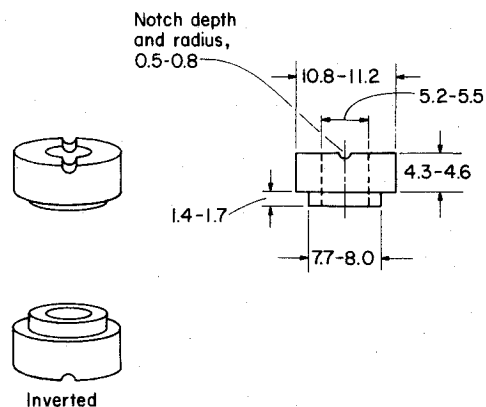
#### Cathode Support

As mentioned at the beginning of the Mechanical Design section, the approach used does not require vacuum-tight electrical feedthroughs. A typical cathode support assembly, consistent with this approach, is indicated in Fig. 16. The feedthrough insulators and sputter shields are all separate and replaceable in the event of breakage. The only welded or brazed connection is between the torque plate and the long M5×0.8 screw. The torque plate and the short screw assembly can be omitted, if desired, but it does serve to keep the long M5×0.8 screw from rotating during cathode replacement. (The M5×0.8 designation refers to a metric screw with a nominal 5 mm outside diameter and a 0.8 mm lead. A third number would indicate length in mm.)

Details of the insulators and sputter shields are shown in Figs. 17 and 18. Tolerances on the insulators are sufficient to permit all machining of  $\geq 96\%$  pure  $\text{Al}_2\text{O}_3$  to be before firing. Other notes for insulator fabrication follow: break all corners to approximately 0.3 mm radius; runout on flat surfaces is 0.05 mm or less; and cylindrical surfaces are coaxial to 0.13 mm or less. A lower purity of  $\text{Al}_2\text{O}_3$  than 96% can result in a short lifetime due to arcing across the insulator surface.

The sputter shields should be drawn from 0.25-mm-thick 304 annealed stainless steel. Low production runs of sputter shields can be accomplished economically with dies in which the material thickness being drawn serves to align and guide the male part of the die.

The cathode support shown in Fig. 16 has been used for heater currents up to 25 A. It may be possible to use this design for higher currents, but there are no data at present to support higher currents. For other screw diameters, scaling laws indicate the same radiation temperature for resistance heating of the screw if the current is varied as the  $3/2$  power of the screw diameter.



a) Male

b) Female

Fig. 17 Cathode feedthrough insulators (all dimensions in mm).

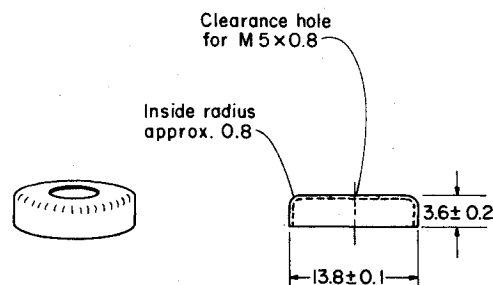


Fig. 18 Cathode sputter shield (all dimensions in mm).

The cathode support design shown in Fig. 16 is intended primarily for the main, or discharge-chamber, cathode. The cathode itself should extend far enough beyond the pole pieces so as to be outside most of the magnetic field, assuming a multipole chamber is used. A distance equal to 1.5-2 times the pole-piece spacing is usually adequate for this purpose. If a small axial-field discharge chamber is used, the cathode should be located near the discharge-chamber axis.

Access to the main cathode is usually possible by removing the ion optics. But this can be excessively tedious, as well as risking damage to the relatively delicate optics. The preferred approach is to have the cathode supports attached to a separate plate, which can be dismantled for cathode replacement by removing 2-4 screws. Push-on connectors are convenient for the associated wiring connections.

The neutralizer can also be supported in a manner similar to that shown in Fig. 16. Because of the exposed location of neutralizers, it is usually not necessary to make special provision for easy access.

#### Anode Support

A typical anode support is indicated in Fig. 19. The insulators and sputter shields are identical to those used for the cathode support except that the central holes in the insulators are all 3.2-3.5 mm and the holes in the sputter shields are M3×0.5 clearance holes.

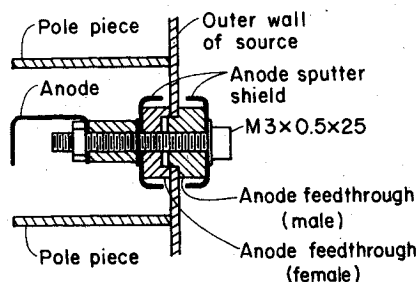


Fig. 19 Anode support assembly.

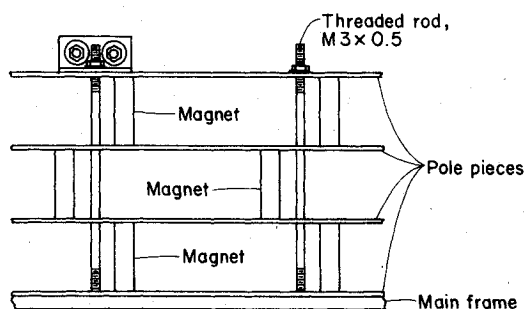


Fig. 20 Pole-piece assembly.

Table 9 Maximum span-to-gap ratios

Ion-optics construction	Max $d_b/l_g$
Flat Mo	60
Dished Mo	600
Flat graphite	100
Flat pyrolytic graphite <sup>a</sup>	200

<sup>a</sup>Oriented with high thermal conductivity and high modulus of elasticity in the plane of the grid.

The pole pieces are assumed to be 25 mm wide and 25 mm apart in Fig. 18. With these dimensions, feedthroughs and sputter shields of the sizes described above will fit with adequate clearances between parts. A U-shaped anode of 0.5-mm-thick stainless steel is assumed for Fig. 18. An anode of this shape is excellent for a rectangular source, but inconvenient for a source with a circular cross section. For the latter, a flat section of stainless steel would be recommended, at least 1.5 mm thick for up to a 30-cm source.

#### Pole-Piece Assembly

A typical assembly of magnets and pole pieces is indicated in Fig. 20. The pole pieces are recessed to hold the magnets in place. (This recessing is usually ignored in calculating the saturation requirement for pole piece thickness.) The magnets for adjacent pairs of pole pieces are offset to avoid doubling the required pole piece thickness. With magnets offset, the structure is less rigid, permitting some compensation for thermal expansion.

#### Ion Optics

The ion optics usually require the closest tolerances and the most careful design of the entire ion source. A basic concept in the ion-optics design is that of span-to-gap ratio, where the gap is the spacing between grids and the span is the beam dimension. For low voltage operation, the smallest possible gap is usually desired to give maximum ion current density. Beyond some rough minimum limit for a given beam diameter, the thermal expansion and warping problems encountered will outweigh any possible performance gain. This minimum gap has been found experimentally to be proportional to the beam diameter for a wide range of design

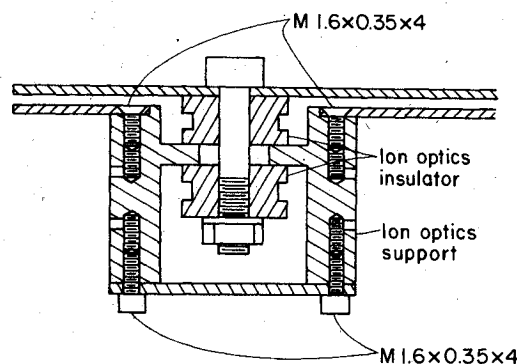


Fig. 21 Ion-optics support assembly.

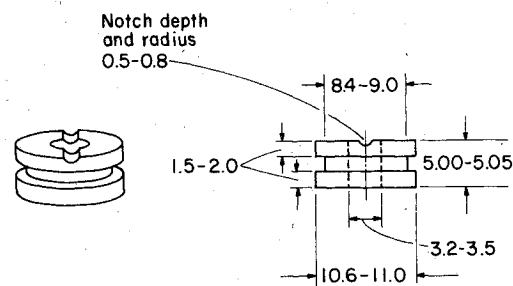


Fig. 22 Ion-optics insulator (all dimensions in mm).

parameters. Some examples of the approximate maximum span-to-gap ratios,  $d_b/l_g$ , are given in Table 9.

For rectangular beam grids, the span-to-gap for the short beam dimension should be less than the value given above, since support is provided on only two sides instead of all the way around (as in a circular beam). In the absence of any further information, the short-dimension span-to-gap ratio is recommended to be half that given in the above table.

For a design example, flat graphite or pyrolytic graphite will be assumed. A rigid flat surface is assumed for mounting the screen grid. The screen should be drawn up against this surface with a sufficient number of screws to prevent buckling due to compressive stresses in the plane of the screen grid. (In the absence of any design details, 8-12 screws should be considered for a 20-30 cm source.) At the same time, these screws should be loose enough to permit relative thermal expansion between the screen grid and the flat surface to which it is mounted. For a mounting surface, a several-mm-thick plate is recommended for a 10-30-cm source. If the mounting surface is a flange on the end of a cylindrical section, the thickness could be reduced to 1.5-2 mm for the same size source.

There is normally a temperature difference of the order of 100°C between the screen grid and the accelerator grid. With flat grids and a single uniform temperature during ion-optics assembly, this temperature difference results in the screen compressive stress mentioned above, together with an accelerator tension stress. If a decelerator is used, the decelerator will be in tension, the screen in compression, and the accelerator at some intermediate stress.

For mounting the accelerator grid to the screen grid, or the decelerator grid to the accelerator grid, the ion-optics support assembly shown in Fig. 21 is suggested. The ion-optics insulator is also shown in Fig. 22. All tolerances and fabrication procedures are the same as for the cathode feedthrough, with the exception of the 5.00-5.05-mm dimension, which has to be machined after firing. The groove around the outside of the insulator is not essential, but should reduce the probability of shorting due to sputter deposition of conductor on the insulator.

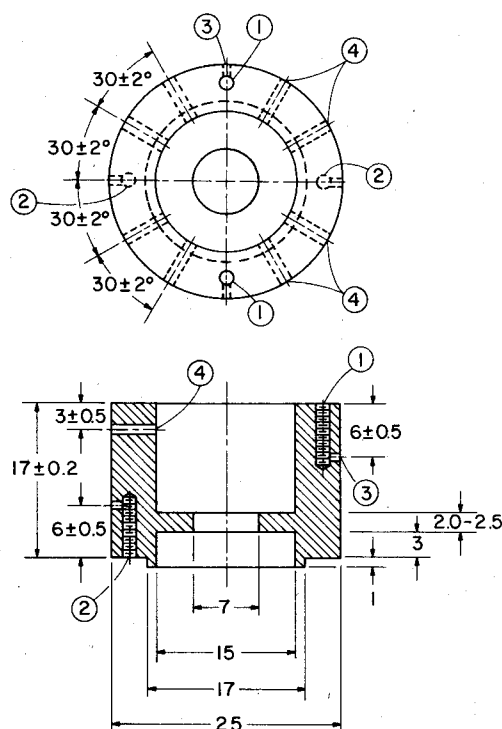


Fig. 23 Ion-optics support (all dimensions in mm).

The ion-optics support is shown in Fig. 23. All dimensions are consistent with a 1 mm grid thickness and a 1 mm gap between grids. The circled numbers in Fig. 23 correspond to the following notes: ① Two holes drilled and tapped for M1.6×0.35 threads, with useful threads at least 4 mm deep. Circumferential locations shown in top view, on 22-mm-diam circle. ② Four holes drilled and tapped for M1.6×0.35 threads, with useful threads at least 4 mm deep. Two circumferential locations shown in top view. Other two hidden behind holes for note ① in top view, with all four on 22-mm-diam circle. ③ Outgassing holes, 1 mm diam, to all drilled and tapped holes. ④ Eight outgassing holes, 1 mm diam, to center cavity. The material is assumed to be type 304 stainless steel.

As discussed previously, the accelerator grid is in tension relative to the screen grid. (The accelerator grid is less in tension if there is a decelerator grid, but there is still a difference.) Because of this difference in stress and because the screen grid is usually thinner within the beam area, more screen grid mounting screws are required than ion-optics supports between grids. For a 20-30-cm-diam beam, 6-8 mounts are suggested. For beam diameters larger than 30 cm, a different mounting design with more accommodation for radial thermal expansion should be considered.

#### Charge-Exchange-Plasma Shielding

A charge-exchange plasma is generated by a broad-beam ion source, owing to the interaction of the beam ions with either the escaping neutrals or the background gas in the vacuum chamber. This plasma constitutes a low-grade conductor that extends throughout most of the vacuum chamber. Positive electrodes, in particular, tend to draw significant stray electron currents when exposed to this plasma, with the currents often precipitating arcs. To prevent these currents and arcs, it is desirable to shield all positive electrodes.

For positive wires, this covering can be quartz or alumina tubing. To retain flexibility, ceramic beads with interlocking conical ends can also be used. If the temperature and outgassing requirements are moderate, polyimide insulation can be used over standard wire.

For larger electrodes, it is customary to use enclosures in which at least part of the enclosure is perforated or is made of screening—to permit rapid outgassing. The critical parameter in such screening is the size of the apertures. If these apertures are larger than roughly the Debye shielding distance, the plasma will “leak through” a grounded and screened enclosure to reach positive electrodes within. If the apertures are smaller than the Debye distance, the enclosure will effectively behave as a continuous surface with respect to plasma.

The production of a charge-exchange plasma has been worked out for an ion source exhausting into a vacuum.<sup>28</sup> A case of more interest here appears to be the generation of a charge-exchange plasma by an ion beam passing through a neutral background gas of known density. The density may be obtained from an ion gage ( $3.29 \times 10^{22} \text{ m}^{-3}$  times the pressure in Torr for a 20°C gage calibration), or it may be calculated using the neutral loss from the discharge chamber if the vacuum-chamber background is negligible.

Assuming an ion beam with a current  $J_b$  and a diameter  $d_b$  passing through a neutral background gas of density  $n_0$ , the production rate for a charge-exchange cross section  $\sigma_{ce}$  and a beam length  $L$  is, for a small fraction of charge exchange,

$$\dot{N}_{ce} = J_b L n_0 \sigma_{ce} / e \quad (22)$$

Assuming these charge-exchange ions leave the outer cylindrical surface of the ion beam with the ion acoustic velocity given by Eq. (1), the density at this location is

$$n_{ce} = J_b m_i^{1/2} n_0 \sigma_{ce} / \pi d_b^{3/2} T_e^{1/2} \quad (23)$$

where  $T_e$  is in eV and all other parameters are in SI units. With the substitution of various constants, this becomes

$$n_{ce} = 2.023 \times 10^{14} J_b m_i^{1/2} n_0 \sigma_{ce} / d_b T_e^{1/2} \quad (24)$$

where  $m_i$  is now in amu. For further substitution, assume 500-eV  $\text{Ar}^+$  ions passing through the Ar neutral background of  $10^{-4}$  Torr, with a beam diameter of 8 cm and a current density of 1 mA/cm<sup>2</sup>. Typical values of 1 eV and  $2.3 \times 10^{-19} \text{ m}^2$  for  $T_e$  and  $\sigma_{ce}$  then yield

$$n_{ce} = 6.1 \times 10^{14} \text{ m}^{-3} \quad (25)$$

Substitution in the equation for the Debye shielding distance then yields a value of about 0.3 mm. It should be clear that a very fine mesh will be required to contain the charge-exchange plasma close to the ion beam. This requirement will ease somewhat with increasing radial distance from the ion beam and even more behind the ion source, but it is a basic environmental problem associated with broad-beam ion sources.

#### Concluding Remarks

Design techniques for the various components of broad-beam electron-bombardment sources are presented. These techniques have emphasized simple and easily used concepts, together with numerical examples and drawings of sample designs. These design techniques, numerical examples, and sample designs should be considered as representative of current technology. Used in this manner, they can serve to facilitate rapid development of design skill in this rapidly growing field of broad-beam ion-source technology.

#### Acknowledgment

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May 25-27	AIAA Annual Meeting and Technical Display (Feb.)	Convention Center Baltimore, Md.		
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May 10-12	AIAA Annual Meeting and Technical Display	Long Beach, Calif.		
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